



EGP30AH THRU EGP30MH

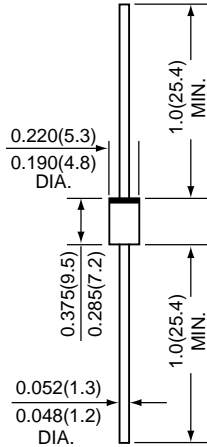
SINTERED GLASS PASSIVATED JUNCTION HIGH EFFICIENT RECTIFIER

Reverse Voltage - 50 to 1000 Volts

Forward Current - 3.0 Amperes

PATENTED

DO-201AD



*Dimensions in inches and (millimeters)

SUPEREX II™



FEATURES

- * Halogen-free type
- * Lead free product, compliance to RoHs
- * GPRC (Glass Passivated Rectifier Chip) inside
- * Glass passivated cavity-free junction
- * Superfast recovery time for high efficiency
- * Low forward voltage, high current capability
- * High surge current capability
- * High temperature soldering guaranteed: 260°C/10 seconds, 0.375" (9.5mm) lead length, 5lbs. (2.3 kg) tension
- * Plastic package has Underwriters Laboratory Flammability Classification 94V-0

MECHANICAL DATA

Case : JEDEC DO-201AD molded plastic over glass body

Terminals : Tin Plated, solderable per MIL-STD-750, Method 2026

Polarity : Color band denotes cathode end

Weight : 0.04 ounces , 1.12 grams

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified.	SYMBOLS	EGP30							UNITS
		AH	BH	DH	GH	JH	KH	MH	
Maximum repetitive peak reverse voltage	V _{RRM}	50	100	200	400	600	800	1000	Volts
Maximum RMS voltage	V _{RMS}	35	70	140	280	420	560	700	Volts
Maximum DC blocking voltage	V _{DC}	50	100	200	400	600	800	1000	Volts
Maximum average forward rectified current 0.375" (9.5mm) lead length (SEE FIG.1)	I (AV)	3.0							Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	125				115			Amps
Maximum instantaneous forward voltage at 3.0 A	V _F	1.0		1.25		1.7			Volts
Maximum DC reverse current at rated DC blocking voltage	I _R	5		50		120			uA
				120		-			
Maximum reverse recovery time (NOTE 1)	t _{rr}	50				75			nS
Typical junction capacitance (NOTE 2)	C _J	75							pF
Typical thermal resistance (NOTE 3)	R _{θJA} R _{θJL}	20				8			°C / W
Operating junction and storage temperature range	T _J ,T _{STG}	-65 to +175							°C

NOTES : (1) Reverse recovery test condition : IF 0.5A, IR=1.0A, I_{rr}=0.25A

(2) Measured at 1.0 MHz and applied reverse voltage of 4.0 Volts

(3) Thermal resistance from junction to ambient and from junction to lead at 0.375" (9.5mm) lead lengths, P.C.B. mounted.

REV. 0

RATINGS AND CHARACTERISTIC CURVES EGP30AH THRU EGP30MH

FIG.1 - FORWARD CURRENT DERATING CURVE

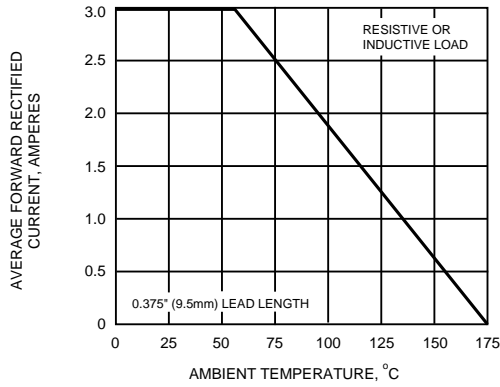


FIG.2 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

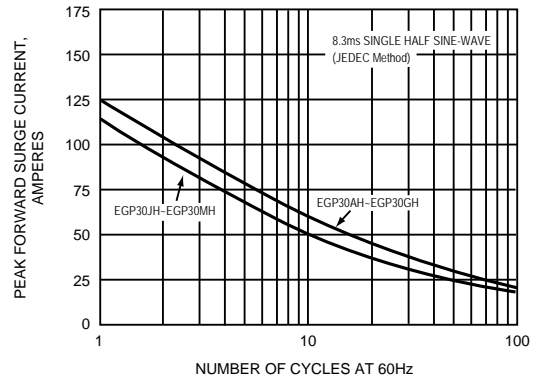


FIG.3 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

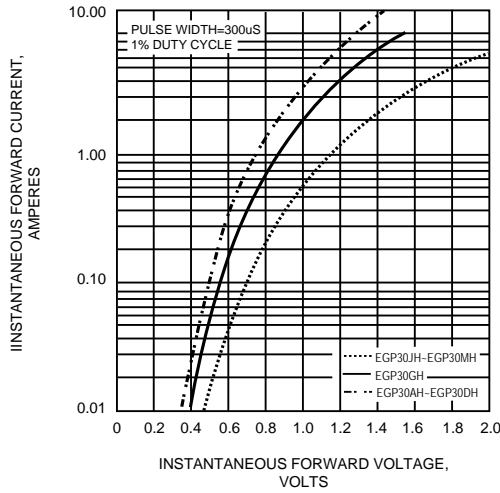


FIG.4 - TYPICAL REVERSE CHARACTERISTICS

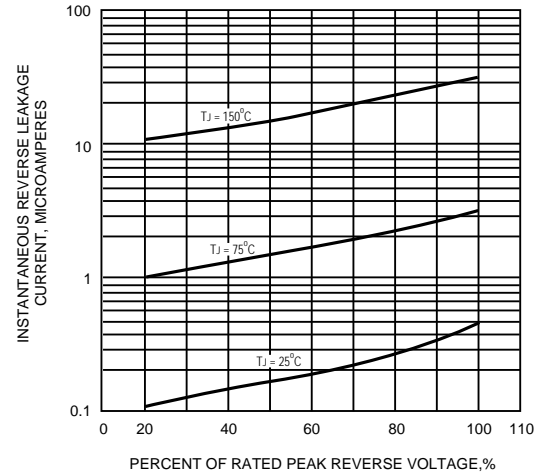


FIG.5 - TYPICAL JUNCTION CAPACITANCE

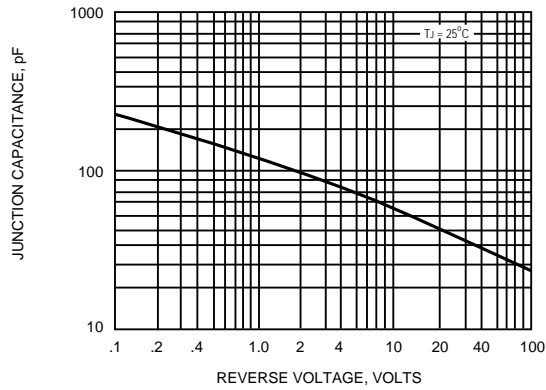


FIG.6 - TYPICAL TRANSIENT THERMAL IMPEDANCE

